

Features

1. Opaque type, SOP package.
2. Subminiature type.
(The volume is smaller than that of our conventional DIP type by as far as 30%)
3. Current transfer ratio.
(CTR: MIN. 50% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)
4. Isolation voltage between input and output. (Viso: 3750V_{RMS})

Part Numbering System: Page 2. **Part Marking System:** Page 3.

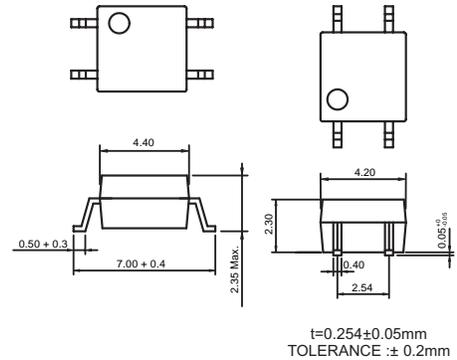
Applications

1. Hybrid substrates that require high density mounting.
2. Programmable controllers.

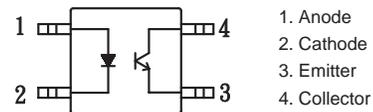
Classification table of current transfer ratio is shown below.

Model NO.	CTR (%)
A	80 TO 160
B	130 TO 260
C	200 TO 400
D	300 TO 600
E	50 TO 600

Outside Dimension: Unit (mm)



Schematic: Top View



Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	60	V
	Emitter-collector voltage	V_{ECO}	5	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		P_{tot}	170	mW
Isolation voltage 1 minute		Viso	3750	V _{rms}
Operating temperature		T _{opr}	-30 to +100	°C
Storage temperature		T _{stg}	-40 to +125	°C
Soldering temperature 10 seconds		T _{sol}	260	°C

Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F = 20\text{mA}$	—	1.2	1.4	V
	Reverse current	I_R	$V_R = 4\text{V}$	—	—	10	uA
	Terminal capacitance	C_t	$V=0, f=1\text{kHz}$	—	30	250	pF
Output	Collector dark current	I_{CEO}	$V_{CE} = 20\text{V}, I_F = 0$	—	—	0.1	uA
	Collector-emitter breakdown voltage	BV_{CEO}	$I_C = 0.1\text{mA}, I_F = 0$	60	—	—	V
	Emitter-collector breakdown voltage	BV_{ECO}	$I_E = 100\text{uA}, I_F = 0$	5	—	—	V
Transfer characteristics	Current transfer ratio	CTR	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$	50	—	600	%
	Collector-emitter saturation voltage	$V_{CE}(\text{sat})$	$I_F = 20\text{mA}, I_C = 1\text{mA}$	—	0.1	0.3	V
	Isolation resistance	Riso	DC500V, 40 to 60%RH	5×10^{10}	10^{11}	—	ohm
	Floating capacitance	C_f	$V=0, f=1\text{MHz}$	—	0.6	1.0	pF
	Response time (Rise)	t_r	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\text{ohm}$	—	5	20	us
	Response time (Fall)	t_f		—	4	20	us

